

Office of **NUCLEAR ENERGY**



Advanced Sensors and Instrumentation

Front End Digitizer (FREND)

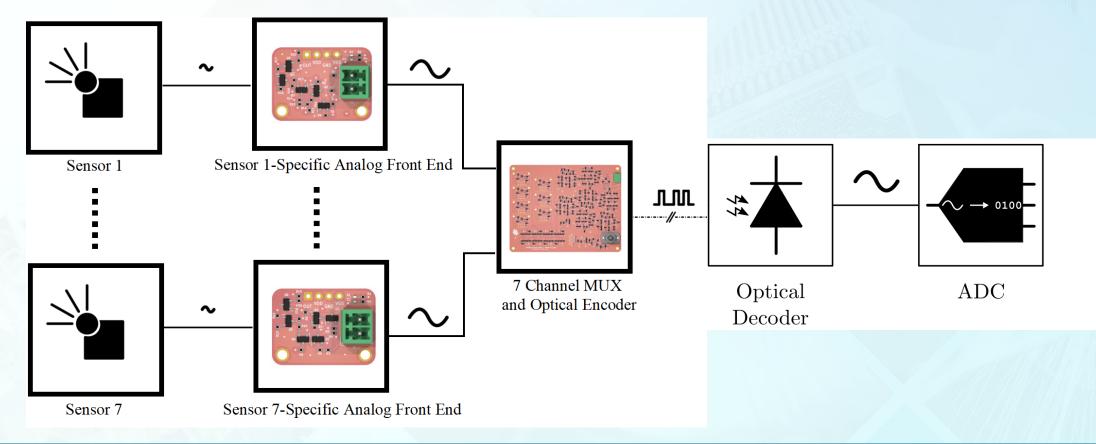
Advanced Sensors and Instrumentation (ASI) Annual Program Webinar

October 30th – November 2nd

Callie Goetz, PhD Oak Ridge National Laboratory

FREND Overview

- Goal: Read out multiple nuclear instruments at a single experimental location over one fiber optic cable (or cable bundle)
 - Thermocouples, SPNDs, SPGDs, RTDs, fission chamber (stretch goal)

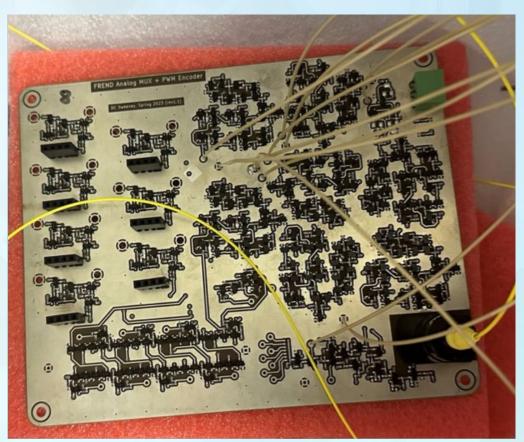


FY23 Effort

- More compact, irradiation-ready redesign
- Preamplifier boards
- Irradiation Goals of FREND System
 - Neutron
 - Neutron/gamma
- Participants:
 - Kyle Reed (electronics design)
 - Dan Sweeney (electronics layout)
 - Callie Goetz (PI)

Irradiation-Ready FREND

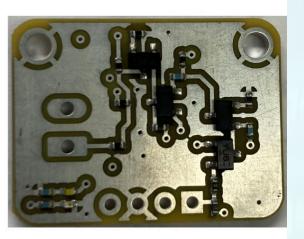
- Combine analog front end/optical encoder onto one board (space saving)
- Increase to 7 channels with 1 index channel, reduce cross talk
- Activation concerns:
 - Lead free solder
 - As little gold as possible (Sn mask)
 - Less copper with larger keep out zones,
- Integrity concerns:
 - Through hole
 - Minimize plastic components
 - No silk screen



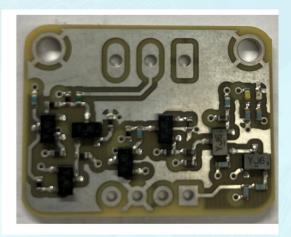
Preamplifier Boards

- Cold junction compensated thermocouple
 - Compensated with thermistor
 - Output: -1 V +1 V
- Current preamplifier SPND, SPGD, fission chamber, ion chamber
 - Input: 4-20 mA current source
 - Output: -1 V +1 V
 - Settable gain

Thermocouple Preamp

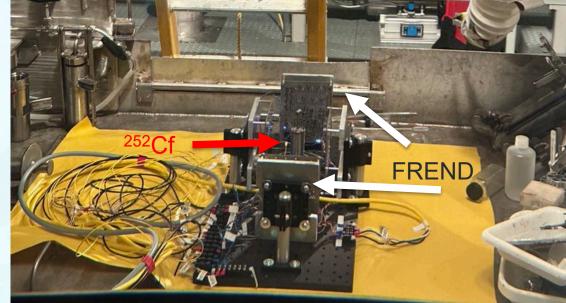


Current to Voltage Preamp

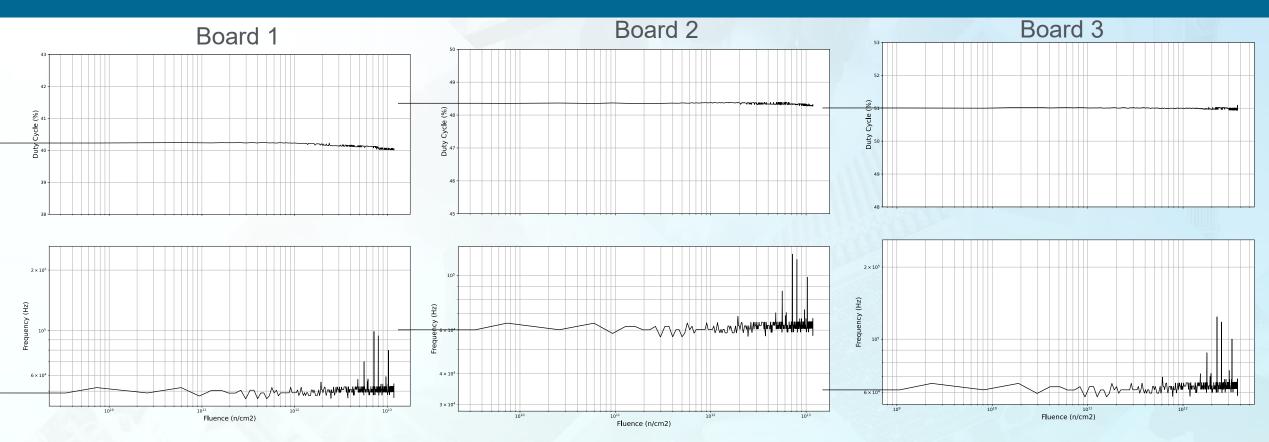


Cf252 Room Temperature Irradiation

- 1.85 mg 252Cf source fast neutrons
- Boards 1, 2 (6 cm), and 3 (19 cm)
- Resistive dividers on all 7 channels holding
 each to a constant voltage
- Automated monitoring (Saleae):
 - Clock
 - Summer
 - FREND output via photodetectors
- 2.8-week irradiation, fluence:
 - Board 1&2: 1.6x10¹³ n/cm²
 - Board 3: 0.5x10¹³ n/cm²
- Survivability test

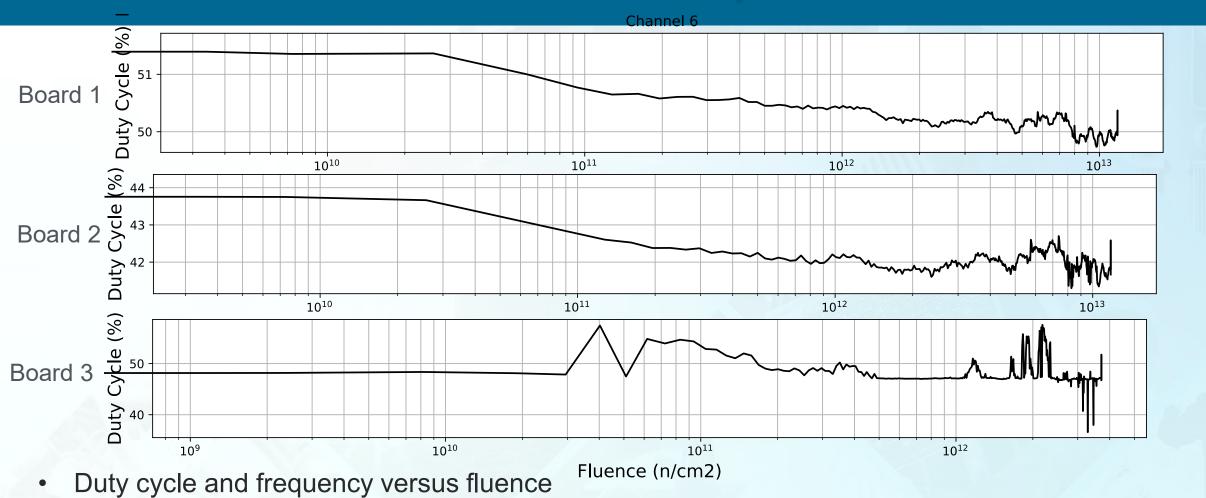


Cf252 Irradiation Results – Clock



- Duty cycle and frequency versus fluence
- Fluence: 10¹³ n/cm²
- No failures observed
- Minimal changes to duty cycle (< 0.1 %)

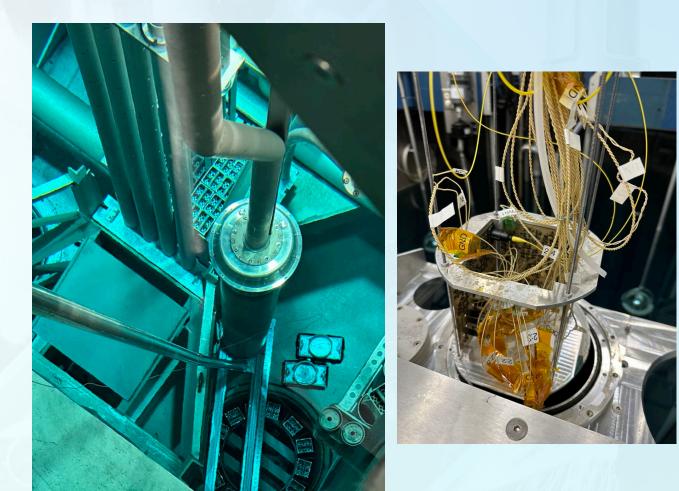
Cf252 Irradiation Results – FREND Output



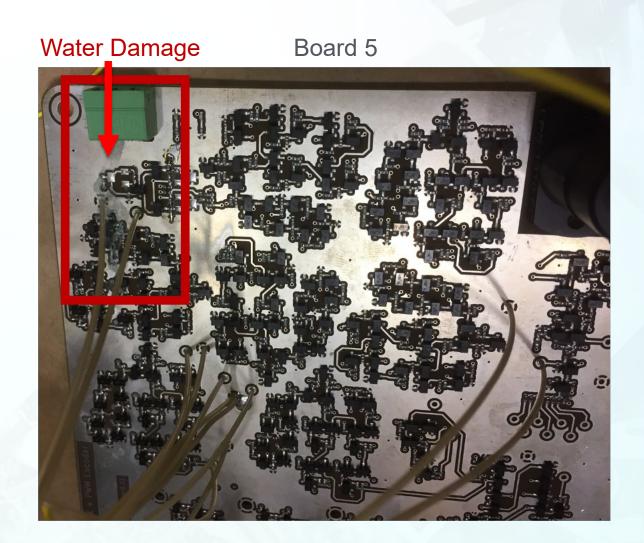
- Fluence: 10¹³ n/cm²
- No failures observed
- Minimal changes to duty cycle (~1%)

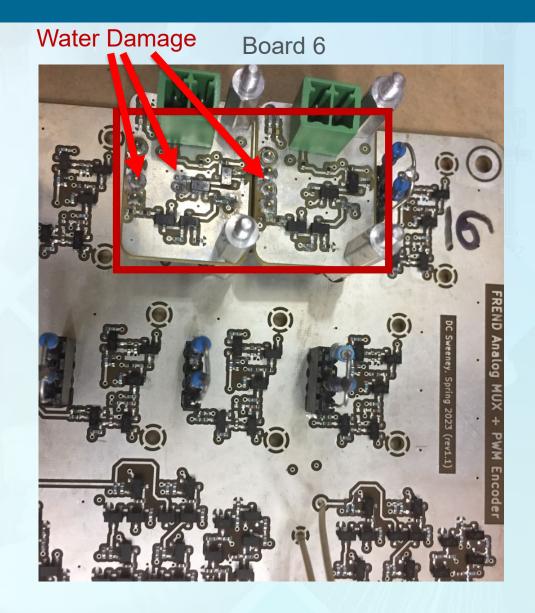
PULSTAR Irradiation

- Boards 5 & 6: water leak
- Boards 8 & 9: 10¹⁶ n/cm²
- Automated monitoring (Saleae):
 - Flip Flops (DFF)
 - Summer
 - Clock
 - FREND output via photodetectors
- Thermocouple preamplifier boards
 with SMU input
- Irradiated 8 hr each day, dry tube backed away from core at night to minimize extra gamma-only exposure

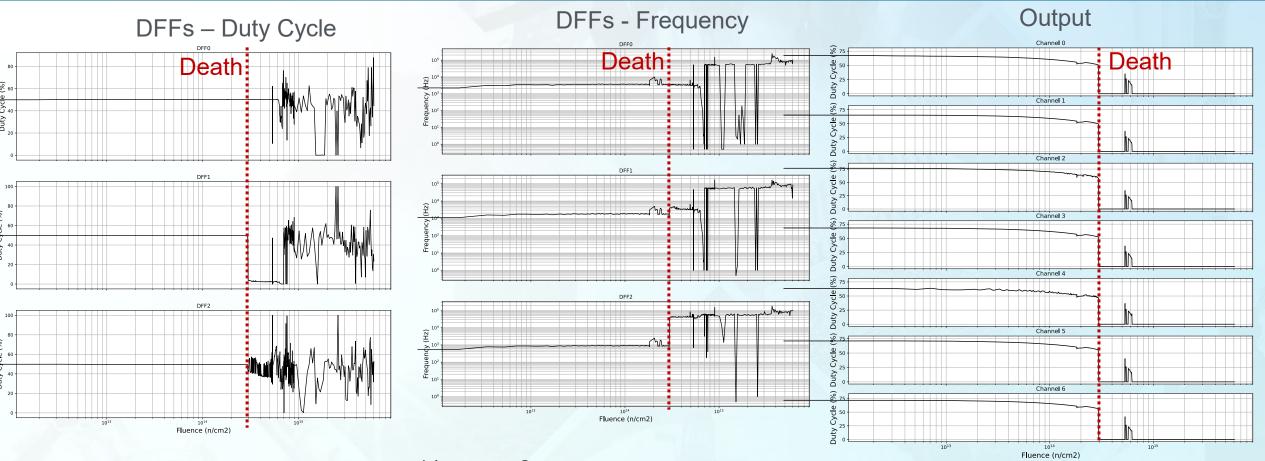


PULSTAR Irradiation – Water leak



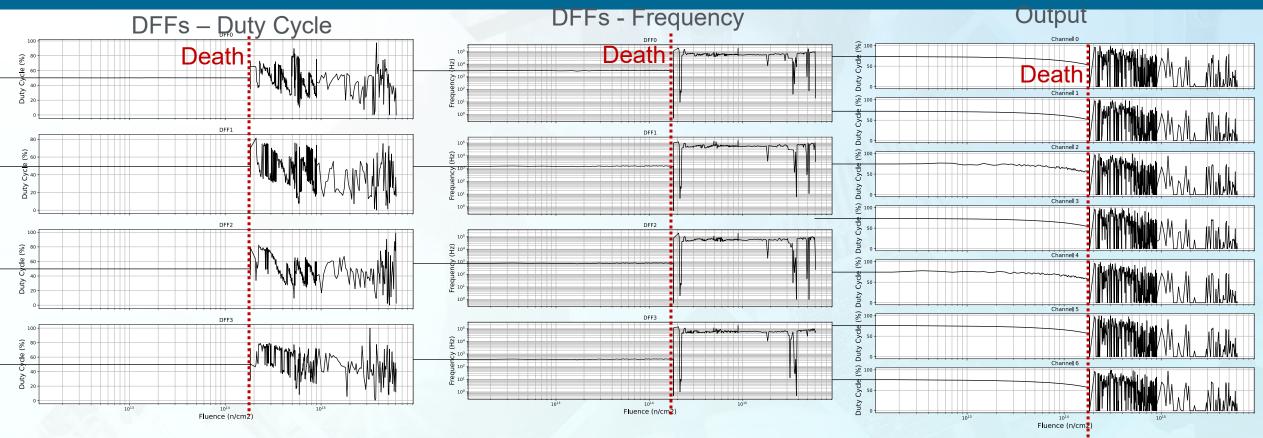


PULSTAR Irradiation Results – Board 8



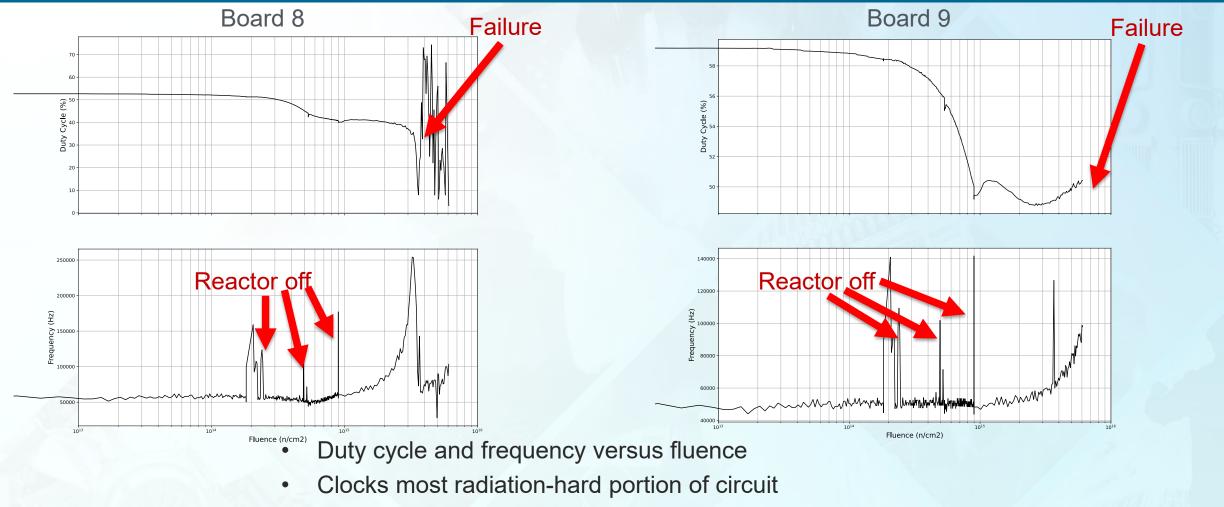
- Failure on DFF1 at 2x10¹⁴ n/cm², causing cascading failure
- Frequency change, suggests change to transistor characteristics (threshold voltage) not complete failure

PULSTAR Irradiation Results – Board 9



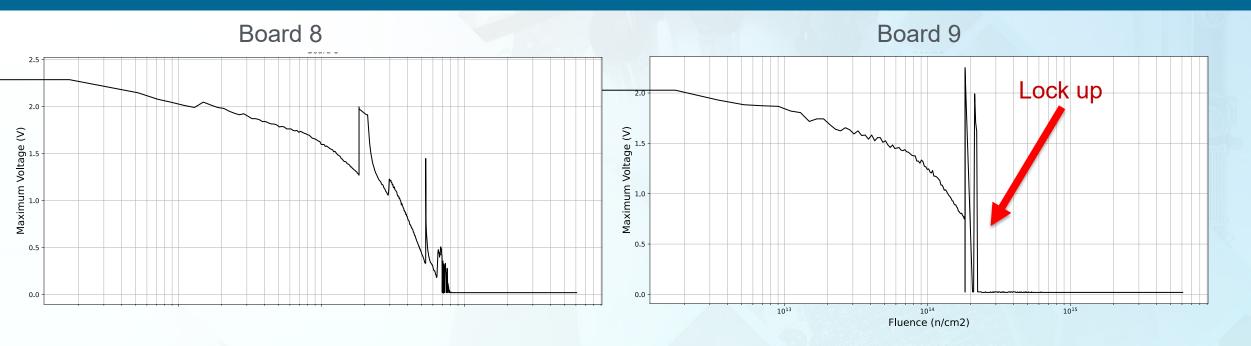
- Power instabilities observed at 1.8x10¹⁴ n/cm² (wild input current variations)
- DFF0 became asymmetric, frequency jumps, suggests failure ahead of DFF0, likely divider after clock
- Reactor turned off, standpipe backed away

PULSTAR Irradiation Results – Clocks



- Board 8 failed at 2.5x10¹⁵ n/cm²
- Board 9 failed between 7x10¹⁵ 1x10¹⁶ n/cm²
- Offer lessons for radiation-hardness of FREND

PULSTAR Irradiation Results – Laser Diode



- Maximum voltage of laser diode versus fluence indicative of health
- Exponential decline of signals suggests drift in sawtooth wave or comparator due to irradiation
- Board 9: locks due to failure in synchronization stage, pulled low

Board number	Irradiation facility	Cause of death	Max fluence (n/cm ²)	Death fluence (n/cm ²)
1	²⁵² Cf	NA	2.5×10^{13}	Survived
2	²⁵² Cf	NA	2.5×10^{13}	Survived
3	²⁵² Cf	NA	2.5×10^{13}	Survived
5	PULSTAR	Water damage	1.3×10^{13}	Survived
6	PULSTAR	Water damage	1.3×10^{13}	Survived
8	PULSTAR	Radiation	1×10^{16}	2×10^{14}
9	PULSTAR	Radiation	1×10^{16}	1.8×10^{14}

Interesting note: no single event effects observed (common in other radiation fields)

Recommendations for FREND

- Results suggest similar neutron-sensitivity in JFETs to CMOS
- Wide bandgap transistors GaN, SiC
- Increase rail voltages, asymmetric logic towards direction of drift in threshold voltage and drain currents
- Incorporate design into rad-hard wide-bandgap ASIC
 - Smaller, allow for on chip redundancy
 - More stable

Concluding Remarks

- Irradiation-ready FREND with modest improvements
- Preamplifier boards to support different I&C
- Irradiated with neutron only (²⁵²Cf) and mixed gamma-neutron (PULSTAR)
- Whole system failure in range 10¹⁴ n/cm²
- Clocks survived beyond 10¹⁵ n/cm² suggest could redesign to survive to similar range
- Neutron effects on JFETs previously unknown
- No SEU's observed
- Recommend wide bandgap FREND ASIC as next step

Successful FREND irradiation campaign demonstrated utility of COTS electronics for nuclear applications!

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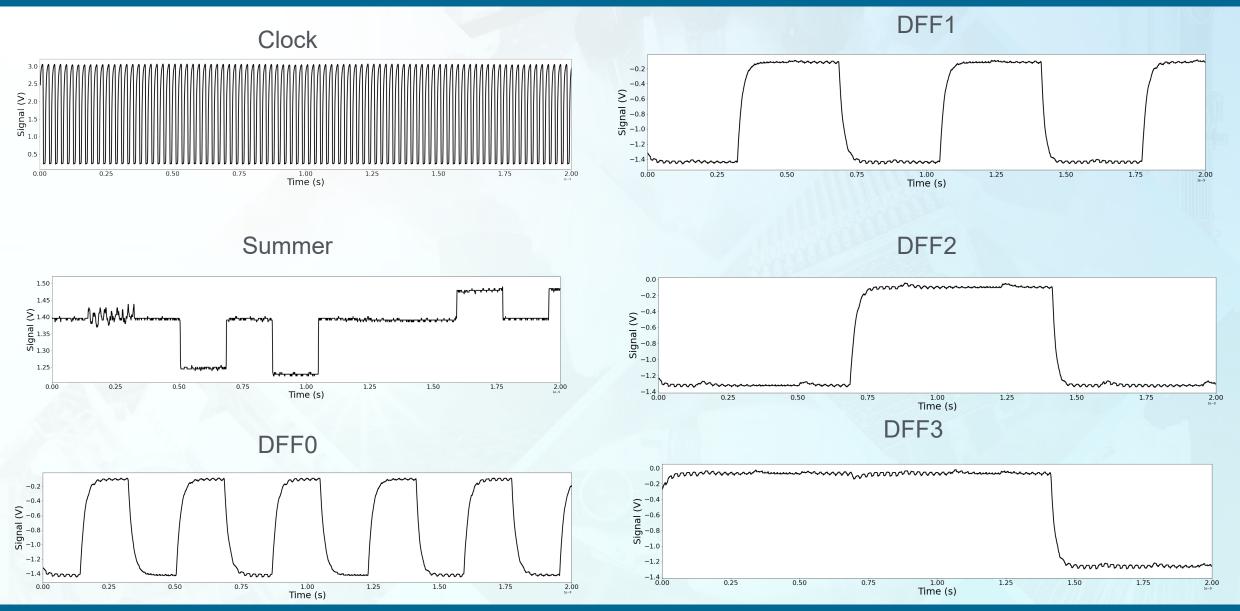


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Thank You



Board Signal Example – Pre Irradiation



Board Output Example - Pre Irradiation

